VLMS233.., VLMR233.., VLMK233.., VLMO233.., VLMY233..

Vishay Semiconductors

AUTOMOTIVE

RoHS

COMPLIANT

HALOGEN FREE

GREEN

(5-2008)

Power Mini SMD LED



DESCRIPTION

The new MiniLED series has been designed in a small white SMT package. The feature of the device is the very small package 2.3 mm x 1.3 mm x 1.4 mm. The MiniLED is an obvious solution for small-scale, high-power products that are expected to work reliably in an arduous environment. This is often the case in automotive and industrial application.

PRODUCT GROUP AND PACKAGE DATA

Product group: LED
Product series: power
Package: SMD MiniLED
Angle of half intensity: ± 60°

FEATURES

- Utilizing latest advanced AllnGaP technology
- Available in 8 mm tape
- Luminous intensity and color categorized per packing unit
- Luminous intensity ratio per packing unit $I_{Vmax.}/I_{Vmin.} \le 1.6$
- ESD-withstand voltage: up to 2 kV according to JESD22-A114-B
- Preconditioning according to JEDEC[®] level 2a
- · IR reflow soldering
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Traffic signals and signs
- · Interior and exterior lighting
- · Dashboard illumination
- Indicator and backlighting purposes for audio, video, LCDs switches, symbols, illuminated advertising etc.

PARTS TABLE														
PART	COLOR		(mcd)		at I _F (mA)	WAY	/ELEN	GTH	at I _F (mA)		ORWAF OLTAG (V)		at I _F (mA)	TECHNOLOGY
		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.		MIN.	TYP.	MAX.		
VLMS233T1V1-GS08	Super red	280	450	900	20	626	630	639	20	1.8	2.0	2.6	20	AllnGaP on Si
VLMR233T2V2-GS08	Red	355	650	1120	20	619	625	631	20	1.8	2.0	2.6	20	AllnGaP on Si
VLMK233U1AA-GS08	Amber	450	680	1400	20	611	616	622	20	1.8	2.1	2.6	20	AllnGaP on Si
VLMO233U1AA-GS08	Soft orange	450	760	1400	20	600	605	611	20	1.8	2.1	2.6	20	AllnGaP on Si
VLMO233U2V2-35-08	Soft orange	560	760	1120	20	602	605	609	20	1.8	2.1	2.6	20	AllnGaP on Si
VLMY233T2V2-GS08	Yellow	355	650	1120	20	583	589	594	20	1.8	2.15	2.6	20	AllnGaP on Si

	TINGS (T _{amb} = 25 °C, unless otherw LMK233, VLMO233, VLMY23			
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage (1)	Short term application only	V _R	5	V
DC Forward current	T _{amb} ≤ 60 °C (480 K/W)	I _F	50	mA
Power dissipation		P_V	130	mW
Junction temperature		Tj	125	°C
Operating temperature range		T _{amb}	-40 to +100	°C
Storage temperature range		T _{stg}	-40 to +100	°C
Thermal resistance junction/ambient	Mounted on PC board (pad size > 16 mm ²)	R _{thJA}	480	K/W

Note

(1) Driving the LED in reverse direction is suitable for a short term application only

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OPTICAL AND ELECTRICA VLMS233, SUPER RED	L CHARACTERISTI	CS (T _{amb} = 25 °C	C, unless o	therwis	e specifi	ed)	
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	VLMS233T1V1	Ι _V	280	450	900	mcd
Luminous flux/luminous intensity			φ _V /I _V	-	3	-	mlm/mcd
Dominant wavelength	$I_F = 20 \text{ mA}$		λ_{d}	626	630	639	nm
Peak wavelength	I _F = 20 mA		λ_{p}	-	639	-	nm
Spectral bandwidth at 50 % I _{rel max} .	$I_F = 20 \text{ mA}$		Δλ	-	18	-	nm
Angle of half intensity	$I_F = 20 \text{ mA}$		φ	-	± 60	-	deg
Forward voltage	I _F = 20 mA		V _F	1.8	2	2.6	V
Reverse current	V _R = 5 V		I _R	-	0.01	10	μA

OPTICAL AND ELECTRICA VLMR233, RED	L CHARACTERISTI	CS (T _{amb} = 25 °C	C, unless o	therwis	e specifi	ed)	
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	$I_F = 20 \text{ mA}$	VLMR233T2V2	Ι _V	355	650	1120	mcd
Luminous flux/luminous intensity			φ _V /I _V	-	3	-	mlm/mcd
Dominant wavelength	I _F = 20 mA		λ_{d}	619	625	631	nm
Peak wavelength	$I_F = 20 \text{ mA}$		λ_{p}	-	632	-	nm
Spectral bandwidth at 50 % I _{rel max} .	I _F = 20 mA		Δλ	-	18	-	nm
Angle of half intensity	$I_F = 20 \text{ mA}$		φ	-	± 60	-	deg
Forward voltage	I _F = 20 mA		V _F	1.8	2	2.6	V
Reverse current	V _R = 5 V		I _R	-	0.01	10	μΑ

OPTICAL AND ELECTRICA VLMK233, AMBER	L CHARACTERISTI	CS (T _{amb} = 25 °C	, unless o	therwis	e specifi	ed)	
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	$I_F = 20 \text{ mA}$	VLMK233U1AA	I _V	450	680	1400	mcd
Luminous flux/luminous intensity			φ _V /I _V	-	3	-	mlm/mcd
Dominant wavelength	$I_F = 20 \text{ mA}$		λ_{d}	611	616	622	nm
Peak wavelength	$I_F = 20 \text{ mA}$		λ_{p}	-	622	-	nm
Spectral bandwidth at 50 % I _{rel max.}	I _F = 20 mA		Δλ	-	18	-	nm
Angle of half intensity	I _F = 20 mA		φ	-	± 60	-	deg
Forward voltage	I _F = 20 mA		V _F	1.8	2.1	2.6	V
Reverse current	V _R = 5 V		I _R	-	0.01	10	μΑ

OPTICAL AND ELECTRICA VLMO233, SOFT ORANGI		CS (T _{amb} = 25 °C	, unless o	therwise	e specifi	ed)	
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	-tit-			450	760	1400	mad
Luminous intensity	$I_F = 20 \text{ mA}$	VLMO233U2V2-35	Ιγ	560	760	1120	mcd
Luminous flux/luminous intensity			φ _V /I _V	-	3	-	mlm/mcd
Dominant wavelength	I _F = 20 mA	VLMO233U1AA	2	600	605	611	nm
Dominant wavelength	IF = 20 IIIA	VLMO233U2V2-35	λ _d	602	605	609	nm
Peak wavelength	I _F = 20 mA		λ_{p}	-	611	-	nm
Spectral bandwidth at 50 % I _{rel max} .	I _F = 20 mA		Δλ	-	17	-	nm
Angle of half intensity	I _F = 20 mA		φ	-	± 60	-	deg
Forward voltage	$I_F = 20 \text{ mA}$		V_{F}	1.8	2.1	2.6	V
Reverse current	V _R = 5 V		I _R	-	0.01	10	μΑ

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OPTICAL AND ELECTRIC VLMY233, YELLOW	CAL CHARACTERIS	TICS (T _{amb} = 25 °	°C, unless	otherwis	se specif	fied)	
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	I _F = 20 mA	VLMY233T2V2	Ι _V	355	650	1120	mcd
Luminous flux/luminous intensity			φ _V /I _V	_	3	-	mlm/mcd
Dominant wavelength	I _F = 20 mA		λ_{d}	583	589	594	nm
Peak wavelength	I _F = 20 mA		λ_{p}	-	591	-	nm
Spectral bandwidth at 50 % I _{rel max} .	I _F = 20 mA		Δλ	-	17	-	nm
Angle of half intensity	I _F = 20 mA		φ	-	± 60	-	deg
Forward voltage	I _F = 20 mA		V _F	1.8	2.15	2.6	V
Reverse current	V _R = 5 V		I _R	-	0.01	10	μA

COLOR CLAS	SIFICATION					
			DOMINANT WA	VELENGTH (nm)		
GROUP	AM	AMBER		DRANGE	YELLOW	
-	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.
1	611	618				
2	614	622	600	603	583	586
3			602	605	585	588
4			604	607	587	590
5			606	609	589	592
6			608	611	591	594

Note

Wavelengths are tested at a current pulse duration of 25 ms

LUMINOUS	UMINOUS INTENSITY CLASSIFICATION							
GROUP	LUMINOUS INTENSITY (mcd)							
STANDARD	OPTIONAL	MIN.	MAX.					
т	1	280	355					
'	2	355	450					
11	1	450	560					
	2	560	710					
V	1	710	900					
V	2	900	1120					
Α	А	1120	1400					
A	В	1400	1800					

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VLMS233T1V1	LS M67F-S2U2-1
VLMO233U2V2-35	LO M67F-U2AB-24
VLMY233T2V2	LY M67F-T2V2-36

CROSSING TABLE

Note

 Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.

In order to ensure availability, single wavelength groups will not be orderable

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

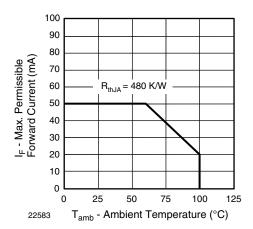


Fig. 1 - Maximum Permissible Forward Current vs.
Ambient Temperature

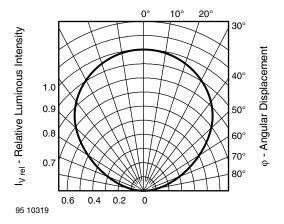


Fig. 2 - Relative Luminous Intensity vs. Angular Displacement

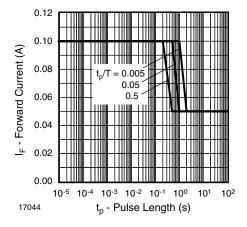


Fig. 3 - Forward Current vs. Pulse Length

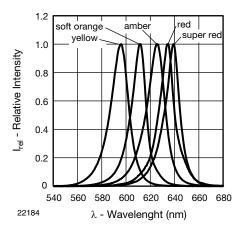


Fig. 4 - Relative Intensity vs. Wavelength

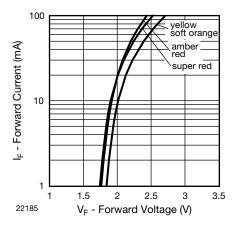


Fig. 5 - Forward Current vs. Forward Voltage

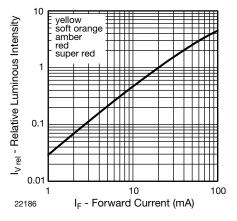


Fig. 6 - Relative Luminous Intensity vs. Forward Current

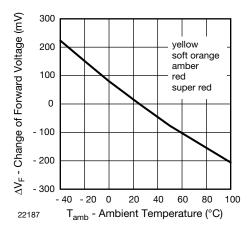


Fig. 7 - Change of Forward Voltage vs. Ambient Temperature

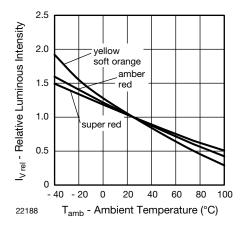


Fig. 8 - Relative Luminous Intensity vs. Ambient Temperature

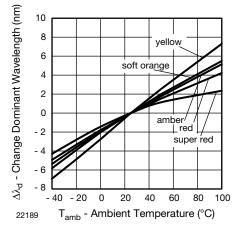


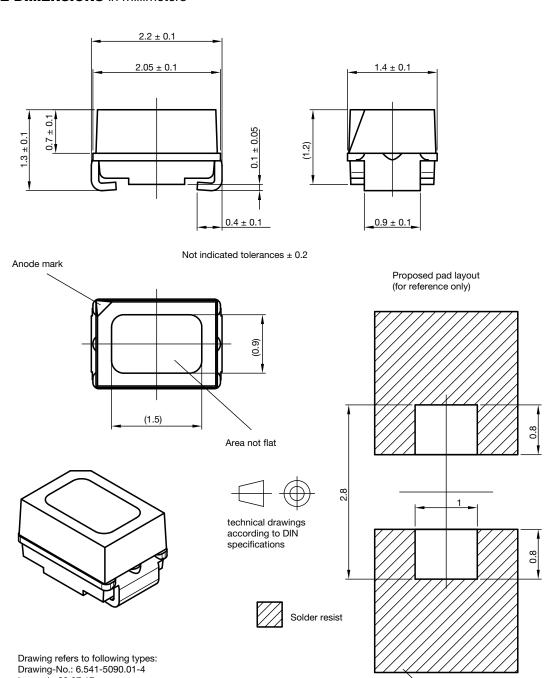
Fig. 9 - Change of Dominant Wavelength vs. Ambient Temperature

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Cu-area > 5 mm²

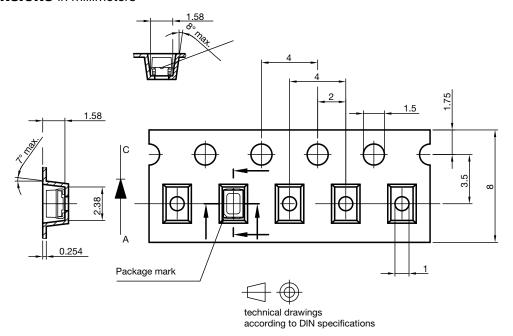
PACKAGE DIMENSIONS in millimeters

Issue: 4; 20.07.17



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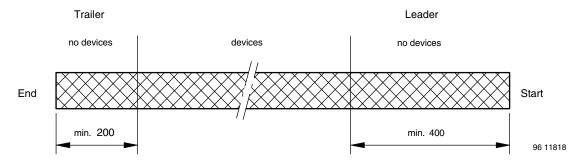
TAPE DIMENSIONS in millimeters



Drawing refers to following types: Mini - SMD - LED with reverse polarity: VLM. 233..., VLM. 235...

Drawing-No.: 9.700-5381.01-4 Issue: 2; 20.07.17

LEADER AND TRAILER DIMENSIONS in millimeters



GS08 = 3000 pcs

COVER TAPE PEEL STRENGTH

According to DIN EN 60286-3 0.1 N to 1.3 N 300 mm/min \pm 10 mm/min 165° to 180° peel angle

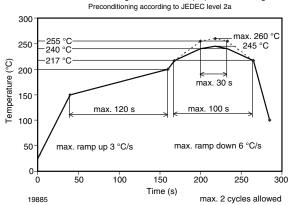
LABEL

Standard bar code labels for finished goods

The standard bar code labels are product labels and used for identification of goods. The finished goods are packed in final packing area. The standard packing units are labeled with standard bar code labels before transported as finished goods to warehouses. The labels are on each packing unit and contain Vishay Semiconductor GmbH specific data.

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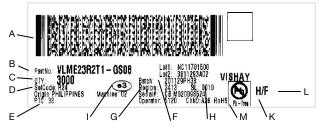
SOLDERING PROFILE



IR Reflow Soldering Profile for Lead (Pb)-Free Soldering

Fig. 10 - Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020)

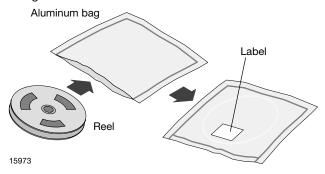
BAR CODE PRODUCT LABEL (example)



- A. 2D bar code
- B. Part number = Vishay part number
- C. QTY = Quantity
- D. Sel. code = selection code (binning)
- E. PTC = Code of manufacturing plant
- F. Batch = date code: year / week / plant code
- G. Region code
- H. SL = sales location
- I. Terminations finishing
- J. Lead (Pb)-free symbol
- K. Halogen-free symbol
- L. RoHS symbol

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

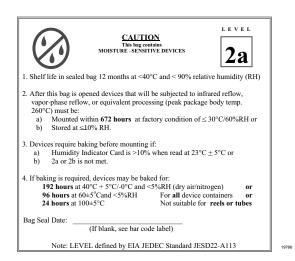
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C / - 0 °C and < 5 % RH (dry air/nitrogen) or

96 h at 60 °C + 5 °C and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electrostatic sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABEL

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.

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